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Synergistic effect of cocatalytic NiSe₂ on stable 1T-MoS₂ for hydrogen evolution†

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Robust and economical catalysts are imperative to realize the versatile applications of hydrogen. Herein, a 1T-MoS $_2$ /N-doped NiSe $_2$ composite was rationally synthesized via a solvothermal method, in which the MoS $_2$ nanosheets have a stable 1T phase structure, and the NiSe $_2$ nanoparticles serve as a cocatalytic support for MoS $_2$. The nonnegligible electronic couplings between NiSe $_2$ and MoS $_2$ could facilitate the optimization of their electronic structure and then improve the hydrogen adsorption. What is more, the nitrogen dopants in the NiSe $_2$ nanoparticles could intensify the intercalation of ammonium ions in the 1T-MoS $_2$ nanosheets, and further enlarge their interlayer spacing, thus the electrolyte could infiltrate into the catalyst more easily and sufficiently. This work provides a new route for rationally designing highly active and low cost hydrogen evolution reaction (HER) catalysts, and enriches the study of transition metal chalcogenides toward HER.

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1. Introduction

Hydrogen is recognized as a promising clean energy resource because of its high gravimetric energy density and no CO₂ release.¹⁻⁴ Among the existing H₂ production methods, electrochemical and photocatalytic hydrogen evolution by water splitting have been widely recognized as the most promising strategies.⁵⁻⁷ Especially, electrochemical technology has significant advantages due to its quick, straightforward and highly efficient fashion.⁸⁻¹⁰ Generally, to achieve a fast H₂ production rate, a catalyst with high efficiency is necessary. Up to now, platinum (Pt)-based catalysts have been widely considered as the best catalysts for HER. However, their limitations such as being expensive and having frustrating durability severely restricted their scale-up commercial applications.¹¹⁻¹³ Thus, the rational design and fabrication of economic and durable HER catalysts are of great importance.

Transition metal dichalcogenides (TMDs) have attracted considerable attention in substituting Pt-based catalysts due to their excellent electrocatalytic properties, popular price, and abundant earth reserves. ¹⁴ Molybdenum disulfide (MoS₂) is one of the most representative TMDs. Notably, the typical lamellar

characterizations and structural polymorphism grant it distinctive characteristics in the electrochemical field.15 Generally, MoS₂ is in a 2H phase, which is thermodynamically stable. 2H-MoS₂ is semiconductor and has a poor conductivity. Besides, the large inert basal planes and small proportion of active edges significantly limits its catalytic efficiency. 16,17 In comparison with 2H-MoS2, the metallic (1T) phase MoS2 has a good conductivity and possesses excellent HER response both on basal plane and at edge sites. However, the microstructure of 1T-MoS₂ is thermally metastable and would gradually convert into 2H-phase even at room temperature.17 Thus, stable 1T-MoS₂ catalysts are highly pursued for the applications in hydrogen evolution. Typically, Wu et al. successfully prepared osmotically swollen MoS2, in which adjacent layers are intercalated by ammonium ions with remarkable lattice expansion. The swollen MoS2 catalyst exhibits excellent HER activity with a small Tafel slope of 45 mV dec⁻¹.18 However, the HER performances are still unsatisfied. Constructing heterogeneous interfaces by introducing another component is an efficient way to boost the electrochemical activity of catalysts. 19-23 As is known to all, HER proceeds with the initial formation of hydrogen intermediates (H*) followed by a Tafel or Heyrovsky step. The synergistic effect between two hybridized components could fine tune their surface adsorption properties by interfacial electronic coupling and facilitate an excellent activity and a high stability towards HER. For example, Song et al. bounded 1T-MoS₂ nanopatches to highly conductive single-walled carbon nanotube films relying on interface engineering and realized a further improved overpotential of 108 mV.23 Regrettably, the single-walled carbon nanotube films exhibit scarce catalytic activity, and just behave as the conductive skeletons at the expense of the catalyst

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weight. Recently, the heterogeneous TMDs with a relatively high conductivity are considered to be used as a cocatalytic support for MoS₂ due to their excellent cocatalytic functionality.^{24,25} Typically, Yang' group chose conductive NiS₂ to construct 1T-MoS₂/NiS₂ hybrid catalyst and realized a low onset potential of 34 mV.²⁶ Although extensive efforts have been devoted, the development of

heterogeneous TMDs catalyst still lies in its early stage.

In this work, N-doped NiSe₂ nanoparticles were selected as the cocatalytic support for 1T-MoS₂ nanosheets. The nonnegligible electronic couplings between NiSe₂ and MoS₂ could facilitate the optimization of their electronic structure and then improve their hydrogen adsorption. In addition, the nitrogen dopants in the NiSe₂ nanoparticles could further enlarge the (002) interlayer spacing of MoS₂, which makes electrolyte infiltrate into the catalyst more easily and sufficiently. This work enriches the study on heterogeneous TMDs catalyst for HER and provides a new option to realize stable 1T-MoS₂.

Experimental

2.1 Chemicals and reagents

Nickel chloride hexahydrate (NiCl $_2\cdot 6H_2O$, 98%), sodium borohydride (NaBH $_4$, 98%), selenium (Se, 99.9%), thiourea (CS(NH $_2$) $_2$, 99%), ammonium molybdate ((NH $_4$) $_6$ Mo $_7$ O $_2$ 4 $\cdot 4$ H $_2$ O, 99%), disodium hydrogen phosphate dodecahydrate (Na $_2$ HPO $_4\cdot 7$ H $_2$ O), sodium phosphate monobasic dihydrate (NaH $_2$ PO $_4\cdot 2$ H $_2$ O) are all analytical grade. They were used without further purification.

2.2 Materials syntheses

Bare NiSe₂ nanoparticles were synthesized by solvothermal method. First, 0.316 g selenium and 0.189 g NaBH₄ were dissolved in 30 mL N,N-dimethylformamide (DMF) and stirred for 1 hour. Then, 0.476 g NiCl₂·6H₂O was gradually added into the solution and agitated for 1 hour. After that, the solution was poured into a Teflon-lined autoclave, whose volume is 50 mL. The autoclave was kept at 160 °C for 12 hours. Centrifugal method was adopted to gather the precipitate. Deionized water and ethanol were alternatively used as cleaning fluid. Finally, the collected precipitate was dried at 60 °C in vacuum overnight.

To synthesize $MoS_2/NiSe_2$ composite, 76 mg of as-prepared $NiSe_2$ powder was dispersed in 30 mL deionized water and sonicated for 30 min. Then 62 mg $(NH_4)_6Mo_7O_{24}\cdot 4H_2O$ and 114 mg $CS(NH_2)_2$ were added into the solution and stirred homogeneously. The dispersion was kept at 180 °C for 24 hours. The collection and treatment of the precipitate are the same as above.

The synthesis of bare MoS₂ nanosheets is the same as that for MoS₂/NiSe₂ composite expect for adding NiSe₂ nanoparticles as substrates.

2.3 Fabrication of electrodes

The prepared catalysts and carbon nanotubes were dispersed in the solvent of *N*-methyl-2-pyrrolidone (NMP) including 7 wt% PVDF (mass ratio of catalysts, PVDF, and carbon nanotubes was 8:1:1). After ultrasonic uniformity, the slurry was coated on carbon paper (mass loading: 1 mg cm⁻²), and dried at 60 °C for 12 h under vacuum condition.

2.4 Materials characterization

The crystal structure was characterized by X-ray diffraction (XRD, D/max 2600, Rigaku, Japan) with Cu K α radiation (λ = 1.5418 Å). The micromorphology and elementary composition were determined by scanning electron microscopy (SEM, SU70, Hitachi, Japan) equipped with energy dispersive X-ray spectroscopy (EDS) and transmission electron microscopy (TEM, FEI, Tecnai TF20). The surface chemical states were characterized by X-ray photoelectron spectroscopy (XPS) employing K-alpha X-ray spectrometer (Thermo, USA).

2.5 Electrocatalytic measurements

The VMP3 electrochemical workstation (Bio-logic, France) was used to conduct electrochemical measurements. The experiments were carried out within a typical three-electrode system in 0.5 M H₂SO₄ electrolyte (except where noted). The prepared catalysts coated on carbon paper was used as working electrode with saturated calomel electrode (SCE) and carbon rod as reference and counter electrodes, respectively. The formula E (RHE) = E (SCE) + 0.059 \times pH + 0.241 V was used to convert potentials into the reversible hydrogen electrode defined as (RHE). Polarization curves were attained using a linear sweep voltammetry (LSV) method. All the polarization curves were corrected using 85% ohmic potential drop (iR) compensation. The electrochemical impedance spectroscopy (EIS) was measured at the overpotential of -0.2 V (vs. RHE) with the frequencies ranging from 100 mHz to 100 KHz. Electrochemical surface area (ECSA) was estimated by the cyclic voltammetry (CV) measurements at 20–100 mV s⁻¹. By plotting the different scan rate of anode and cathode current density difference (Δj = $j_{\rm a}-j_{\rm c}$) at 0.15 V (vs. RHE), double-layer capacitance ($C_{
m dl}$) is defined as half of the slopes value. Turnover frequency (TOF) of the catalysts was calculated by employing the CV curves measured in pH = 7 phosphate buffer. The voltage range is from -0.2 to 0.6 V (vs. RHE), and the scan rate is 50 mV s⁻¹. The calculation follows the equation: TOF (s⁻¹) = $(j \times A)/(2 \times n \times F)$, where F is the Faraday's constant (96 485 C mol^{-1}), j (mA cm^{-2}) is the current density obtained by LSV measurement, A (cm²) is the geometric area of the electrodes, and the number of 2 represents that two electrons are required to form one hydrogen molecule from two protons $(2H^+ + 2e^- = H_2)$. Catalytic stability was examined by the CV test at 50 mV s⁻¹ from -0.3 to 0.1 V (vs. RHE) and the chronoamperometry measurement at -100 mV (vs. RHE) for 25 h.

Results and discussion

3.1 Morphologies and structures

Fig. 1a illustrates the preparation process of MoS₂/NiSe₂ composite. Firstly, NiSe₂ nanoparticles were prepared *via* a solvothermal method. The SEM image in Fig. S1† well exhibits their irregular polyhedral morphology with a large amount of ridges and re-entrants. EDS analysis reveals that the as-prepared nanoparticles are slightly nonstoichiometric NiSe₂ with a small amount of nitrogen dopant (Fig. S2†). Secondly, the N-doped NiSe₂ nanoparticles were dispersed into a homogeneous aqueous solution of ammonium molybdate and thiourea to *in*

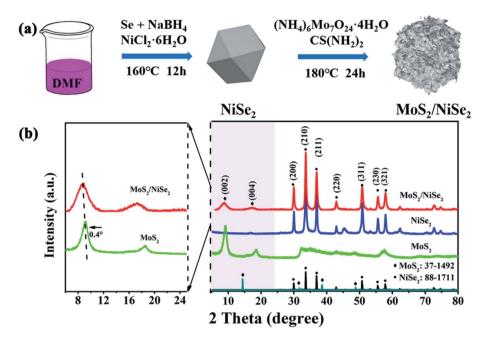


Fig. 1 (a) Diagrammatic drawing of the synthesis process of $MoS_2/NiSe_2$ composite, in which DMF stands for N,N-dimethylformamide. (b) XRD patterns of bare MoS_2 , $NiSe_2$, and $MoS_2/NiSe_2$ composite.

situ grow MoS2 nanosheets on their surface. The resultant compositions were firstly characterized by XRD. In Fig. 1b, the XRD profile consists of dominant sharp diffraction peaks of cubic NiSe₂ (JCPDS 88-1711) and faint signals of MoS₂. Notably, the (002) peak of MoS₂ is located at 8.7°, which shows a remarkable negative shift from the (002) peak of 2H-phase MoS₂ (JCPDS 37-1492), demonstrating that the MoS₂ nanosheets have a 1T-phase structure and the resultant products are 1T-MoS₂/N-doped NiSe₂ composite. The bare MoS₂ nanosheets prepared without N-doped NiSe2 nanoparticles participating also have a 1T-phase structure with their (002) peak located at 9.1°. It powerfully indicates that the MoS2 synthesized in this study, either bare or in composite, are both in 1T phase. More importantly, the 1T-MoS2 is thermodynamically stable, which is proved by almost the same XRD pattern obtained from the sample aged 3 months at room temperature (Fig. S3†).

The morphology of the 1T-MoS₂/N-doped NiSe₂ composite was vividly shown in Fig. 2a. It is clear that a sight of flimsier nanosheets intertwine into an edge-oriented geometry on the outer surface of N-doped NiSe₂ nanoparticles. The nanosheets distribute more homogeneously than those ones prepared without N-doped NiSe₂ nanoparticles participating (Fig. S4†). It should give the credit of this homogeneous distribution to the abundant and highly dispersed nucleation sites provided by the N-doped NiSe₂ nanoparticles. EDS analysis reveals that S, Mo, Se and Ni elements coexist in the composite with a small amount (\sim 6.7 at%) of N element (inset of Fig. 2a), which should be inherited from DMF, thiourea and ammonium molybdate. The elemental mappings in Fig. 2b demonstrate the uniformly dispersion of Ni, Se, Mo, S, and N. The luminosities of Ni, Se, Mo and S elements are markedly higher than that of N element, illustrating the relatively low content of N element. The distributions of Mo and S have a slightly larger size than those of Ni

and Se, corresponding to the decoration of NiSe2 nanoparticles with the MoS₂ nanosheets. The further microstructural information of the 1T-MoS₂/N-doped NiSe₂ composite was characterized by TEM. Fig. 2c shows that the composite consists of internal NiSe2 nanoparticle (dark area) and external translucent MoS₂ nanosheets. The ultrathin MoS₂ nanosheets are less than five layers and tightly wrap the NiSe2 nanoparticle, which generates abundant interfaces between MoS2 and NiSe2. The typical high-resolution TEM image offers a deep insight to these heterogeneous interfaces (Fig. 2d). The lattice distance of 0.27 nm is assigned to the (210) plane of NiSe2, and the one of 1.02 nm is the (002) plane of 1T-MoS₂.^{27,28} Impressively, the (002) lattice distance of 1.02 nm for 1T-MoS₂ is 0.4 nm larger than $2H-MoS_2$ (~ 0.62 nm), and coincides with the diffraction peak located at 8.7° in the XRD curve (Fig. 1b). This increment just well accommodate ammonium ions, whose size is about 0.35 nm.^{29,30} Thus, the enlarged (002) interlayer spacing of MoS₂ in this study should owe to the intercalation of ammonium ions inherited from thiourea or ammonium molybdate. Fig. S5† is the high-resolution TEM image of bare MoS₂ nanosheets. It is noticeable that the (002) interlayer spacing of the MoS2 in composite is further enlarged with a \sim 5% expansion by hybridizing with N-doped NiSe2 nanoparticles. Fig. 2e shows the SAED pattern of the 1T-MoS₂/N-doped NiSe₂ composite, wherein the (110) and (105) planes belong to 1T-MoS2, and the (200), (210), (211) and (220) planes belong to N-doped NiSe₂. The discrete concentric rings well demonstrate the polycrystalline nature of the 1T-MoS₂/N-doped NiSe₂ composite.

The compositions and chemical surface states of 1T-MoS₂/N-doped NiSe₂ composite were analyzed by XPS. Fig. 3a indicates the existence of Ni, Se, Mo, S, and N. Fig. 3b shows the Mo-3d spectra, in which Mo⁴⁺, Mo⁵⁺, and Mo⁶⁺ were included. The peak located at 235.7 eV is corresponding to Mo⁶⁺, which is

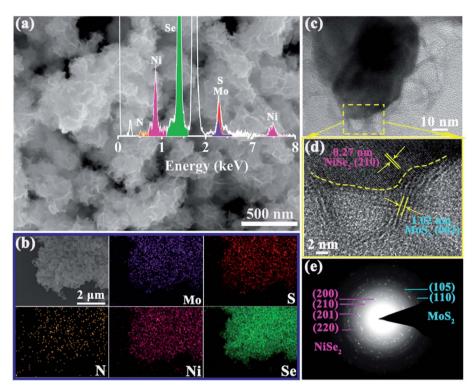


Fig. 2 (a) SEM image, inset shows the relevant EDS spectrum, (b) the corresponding elemental mapping images, (c) TEM image, (d) HRTEM image, and (e) SAED pattern of $MoS_2/NiSe_2$ composite.

derived from surface oxidation and coincided with the detected O element in Fig. 3a. The two doublets located at 232.5/229.5 eV and 231.6/228.5 eV coincide with the $3d_{3/2}$ and $3d_{5/2}$ orbits of Mo⁴⁺ and Mo⁵⁺, respectively.³¹ In the S-2p spectra (Fig. 3c), the 161.2 eV and 162.5 eV peaks belong to the S²⁻ 2p_{3/2} and S²⁻ 2p_{1/2} orbits, respectively.^{32,33} Compared with bare 1T-MoS₂, these peaks all exhibit a red shift in the 1T-MoS₂/N-doped NiSe₂ composite. Fig. 3d shows the Ni-2p profiles, in which the peaks were divided into three doublet peaks corresponding to Ni²⁺,

Ni³⁺ and shakeup satellite. The doublets located at 853.6/871.0 eV and 856.4/874.2 eV are corresponded well with the $2p_{3/2}$ and $2p_{1/2}$ of Ni²⁺ and Ni³⁺, and another doublets belong to the shakeup satellite of Ni $2p_{.}^{27,34}$ In contrast with the red shifts of Mo-3d and S-2p, the three doublets of Ni-2p all show a blue shift as compared with bare NiSe₂. Fig. 3e is the Se-3d XPS spectra. The Se₂²⁻ $3d_{5/2}$ and Se₂²⁻ $3d_{3/2}$ peaks located at 54.7 and 55.6 eV also show a slightly red shifting compared with bare NiSe₂. These red/blue shifts imply the electron transfer between NiSe₂

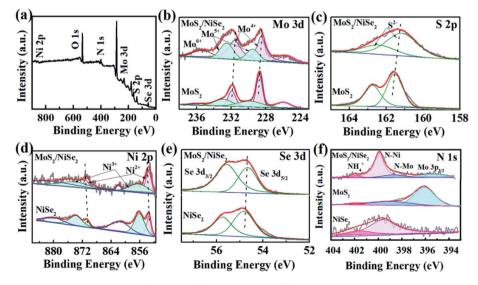


Fig. 3 (a) The survey XPS spectrum of $MoS_2/NiSe_2$, (b) Mo 3d, (c) S 2p, (d) Ni 2p, (e) Se 3d, (f) N 1s XPS spectra of $MoS_2/NiSe_2$ compared with bare MoS_2 or $NiSe_2$.

and MoS₂ at their heterogeneous interfaces and highly enhance the hydrogen adsorption ability. 23,36,37 Additionally, the ratio of Ni²⁺/Ni³⁺ in the composite is 0.56, which significantly larger than that in the bare NiSe₂ (0.37). Higher Ni²⁺/Ni³⁺ ratio always associates with a superior HER activity due to the higher sensitivity of Ni²⁺ to HER than Ni³⁺.38 In Fig. 3f, the N 1s XPS spectra consist of three overlapping peaks. The dominant one is located at 399.4 eV and ascribed to N-Ni bond.39 The nanoid one at 398.2 eV belongs to N-Mo bond.40 The significantly higher intensity of N-Ni than N-Mo bond indicates the relatively higher content of N in NiSe2 than MoS2, which might be the reason why the (002) interlayer spacing of 1T-MoS2 is further enlarged after hybridizing with the N-doped NiSe2 nanoparticles. The small peak located at 401.7 eV is corresponded to the NH₄⁺ embed in the (002) interlayer of MoS₂ or located on the surface of NiSe2, strongly supporting the above assertion that the expanded (002) interlayer spacing is realized by the intercalation of ammonium ions.

3.2 Electrochemical performances

The polarization curve of 1T-MoS₂/N-doped NiSe₂ composite is shown in Fig. 4a. When current density arrives at 10 mA cm⁻², the overpotential is only 94 mV, dramatically surpassing bare MoS_2 (210 mV) and $NiSe_2$ (147 mV). In Fig. 4b, the 1T-MoS₂/N doped NiSe₂ composite, bare MoS₂ nanosheets, and NiSe₂ nanoparticles exhibit a Tafel slope of 58, 76 and 63 mV dec⁻¹. respectively. They are all larger than 40 mV dec⁻¹, implying a Volmer-Heyrovsky mechanism and the rate-determining step of desorption process. Meanwhile, the lower value of 1T-MoS₂/ N-doped NiSe₂ composite indicates its faster HER kinetics than bare MoS2 and NiSe2.25 More than that, the excellent HER activity and low Tafel slope of 1T-MoS₂/N-doped NiSe₂ composite also have obvious advantages to most recently reported low-cost HER catalysts (Table S1†). From Tafel data, the exchange current density (j_0) of 240.5 μ A cm⁻² is obtained for 1T-MoS₂/N-doped NiSe₂ composite. It is significantly larger than that of bare NiSe₂ (177.6 μ A cm⁻²) and 1T-MoS₂ (17.4 μ A

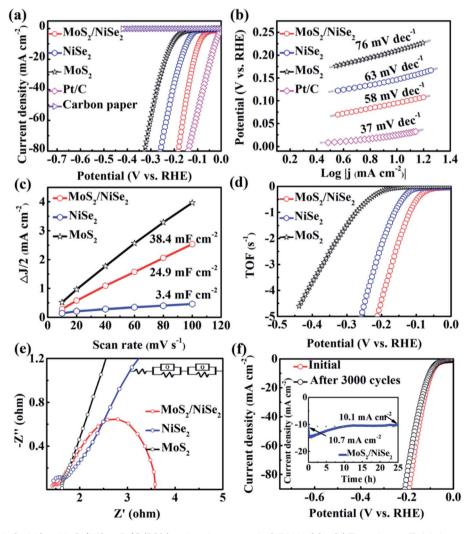


Fig. 4 (a) LSV data of MoS₂, NiSe₂, MoS₂/NiSe₂, Pt/C (20%) and carbon paper in 0.5 M H₂SO₄. (b) The relevant Tafel slopes. (c) Estimated values of double layer capacitance for MoS₂, NiSe₂, MoS₂/NiSe₂. (d) TOF data for HER of MoS₂, NiSe₂, MoS₂/NiSe₂. (e) Nyquist plots (100 mHz to 100 kHz) at -0.2 V (vs. RHE). The inset shows the corresponding equivalent circuit. (f) Polarization curves of MoS₂/NiSe₂ before and after cycling for 3000 times; inset shows chronoamperometric diagram of MoS₂/NiSe₂ at an overpotential of -100 mV (vs. RHE).

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Mo 3d S_{2p} Intensity (a.u.) ntensity (a.u.) ntensity (a.u.) Mo⁵ 800 600 400 200 236 232 228 224 164 162 160 158 Binding Energy (eV) Binding Energy (eV) Binding Energy (eV) Ni 2p Se 3d N 1s Intensity (a.u.) Intensity (a.u.) Intensity (a.u.) N-Ni Se 3d_{5/2} Mo Mo 3p3 872 864 856 58 56 54 52 404 402 400 398 396 394 Binding Energy (eV) Binding Energy (eV) Binding Energy (eV)

Fig. 5 (a) The survey, (b) Mo 3d, (c) S 2p, (d) Ni 2p, (e) Se 3d, (f) N 1s XPS spectra of MoS₂/NiSe₂ composite after cycling measurement.

cm $^{-2}$). In Fig. 4c, the $C_{\rm dl}$ value of 1T-MoS₂/N-doped NiSe₂ composite is derived from the CV curves in Fig. S6† and calculated to be 24.9 mF cm⁻². It is much larger than that of NiSe₂ (3.4 mF cm⁻²) but slightly smaller than MoS₂ (38.4 mF cm⁻²). Therefore, the enhanced HER activity of the composite must not mainly originate from high effective active area.41 TOF is another important parameter for HER catalysts. 42 As shown in Fig. 4d and S7,† the composite needs 147 mV overpotential to reach a TOF value of 2 s⁻¹, while bare NiSe₂ and MoS₂ need an overpotential of 193 and 325 mV, respectively. It suggests that the inherent activity of bare NiSe2 and MoS2 have been dramatically enhanced by forming hybridized composite. This phenomenon can be related to the emergence of the large amount of interfaces between NiSe₂ and MoS₂.⁴³ The nonnegligible electronic coupling generated at these heterogeneous interfaces would result in the enhanced H-chemisorption and thus highly optimize the electrocatalytic activity in the HER. The EIS tests were conducted to analyze the intrinsic conductivity and kinetics of the catalysts. Fig. 4e shows the Nyquist plots of these catalysts at -0.2 V. The high-frequency intersection with the x-axis on the Nyquist plot represents the ohmic resistance (R_s) , which expresses the overall interfacial contacts and the resistance of the electrolyte. The smallest R_s of the three catalysts indicates the strong interfacial contacts of 1T-MoS2/N-doped NiSe2 composite. The highfrequency half-arc is associated with the charge transfer resistance (R_{ct}). According to the equivalent circuit (inset in Fig. 4e), the 1T-MoS₂/N-doped NiSe₂ composite expresses a smaller R_{ct} of 0.25 Ω than bare NiSe₂ (0.37 Ω) and MoS₂ (0.55 Ω). The low-frequency semicircle represents the mass transfer resistance $(R_{\rm mt})$. The mass transfer ability of 1T-MoS₂/N-doped NiSe₂ composite is also superior to the other two catalysts. These improvements after hybridizing should be attributed to the nonnegligible electronic couplings between NiSe2 and MoS2, the superior conductivity of NiSe₂ and the homogeneous distribution and further enlarged (002) interlayer spacing of 1T-MoS₂.

The durability of $1T\text{-MoS}_2/N\text{-doped NiSe}_2$ composite was evaluated by 3000 times CV sweeping at 50 mV s⁻¹. In Fig. 4f,

the polarization curve just exhibits an inappreciable decline after cycling. From another point of view, when 100 mV overpotential was applied, the current density decreases only 0.6 mA cm⁻² after a chronoamperometric process for 25 hours (Inset of Fig. 4f). In Fig. S8,† the cycled 1T-MoS₂/N-doped NiSe₂ composite shows a similar morphology with the fresh composite in Fig. 2a. The structural information was also characterized by XRD test (Fig. S9†). The (002) peak of 1T-MoS₂ is still located at 8.7°, strongly confirming the robust microstructural stability of our 1T-MoS2 as well as the 1T-MoS2/Ndoped NiSe₂ composite. The cycled composite was further analyzed by XPS. Fig. 5a manifests that all the elements of Mo, S, Ni, Se and N are maintained. In Fig. 5b-f, the same compositions and chemical surface states are shown as the profiles in Fig. 3. Especially, the proportion of NH₄⁺ in the N 1s XPS spectrum is kept well after cycling (Fig. 5f), powerfully solidifying the structural stability of the 1T-MoS2 synthesized in this study once again. Based on above analysis, it is reasonable to conclude that the 1T-MoS₂/N-doped NiSe₂ composite can afford the catalytic process for a long time, and its morphology, microstructure, and compositions can be kept well after the durability test.

4. Conclusions

In summary, 1T-MoS₂/N-doped NiSe₂ composite has been successfully fabricated *via* a solvothermal method. The composite achieves a 94 mV overpotential at 10 mA cm⁻², a small Tafel slope of 58 mV dec⁻¹ and a good cycling durability in an acidic situation. Such promising HER performances should be attributed to: (i) the abundant exposed active edge sites arose from the ultrasmall size as well as the highly dispersed geometry of 1T-MoS₂ nanosheets; (ii) the intercalation of ammonium ions and further widened interplanar distance of 1T-MoS₂, which make electrolyte infiltrate into the catalyst more easily and sufficiently; (iii) the cocatalytic support of NiSe₂, which not only provides a conductive support to the

1T-MoS₂ nanosheets, but also serves as a cocatalyst for HER; (iv) the abundant interfaces with nonnegligible electronic coupling/interactions between MoS₂ and NiSe₂, which could facilitate the optimization of their electronic structure and then improve hydrogen adsorption. Given the above, this study offers a new option to realize stable 1T-MoS₂ and design efficient and low cost HER catalysts.

Conflicts of interest

The authors declare no competing financial interest.

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